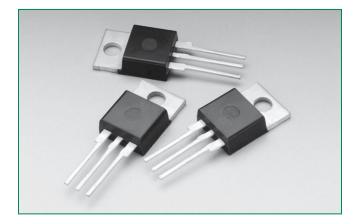
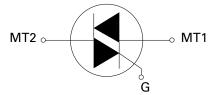
06012LH1LED Series



Agency Approval				
Agency	Agency File Number			
	L Package: E71639			

Main Features						
Symbol	Value	Unit				
I _{T(RMS)}	12	А				
$V_{\rm DRM}/V_{\rm RRM}$	600	V				
I _{GT}	10	mA				

Schematic Symbol



Additional Information







Samples

Description

Q6012LH1LED series is designed to meet low load current characteristics typical in LED lighting applications.

By keeping holding current at 8mA maximum, this Triac series is characterized and specified to perform best with LED loads. The Q6008LH1LED series is best suited for LED dimming controls to obtain the lowest levels of light output with a minimum probability of flickering.

Q6012LH1LED series is offered in the industry standard TO-220AB package with an isolated mounting tab that makes it best suited for adding an external heat sink.

Features

 As low as 8mA max holding current

- UL recognized TO-220AB package
- 110°C rated junction temperature
- di/dt performance of 70A/µs
- QUADRAC version includes intergrated DIAC

Benefits

• Provides full control of light out put at the extreme low end of load conditions.

RoHS 7

- \bullet 2500V $_{\rm AC}$ min isolation between mounting tab and active terminals
- Improves margin of safe operation with less heat sinking required
- Enable survivability of typically LED load operating characteristics
- Simplicity of circuit design & layout

Applications

Excellent for AC switching and phase control applications such as heating, lighting, and motor speed controls.

Typical applications are AC solid-state switches, lighting controls with LED lamp loads, small low current motor in power tools, lower current motor in home/brown goods appliances.

Internally constructed isolated packages are offered for ease of heat sinking with highest isolation voltage.



Absolute Maximum Ratings

Symbol	Paramete	Value	Unit		
I _{T(RMS)}	RMS on-state current (full sine wave)		$T_c = 90^{\circ}C$	12	А
1	Non repetitive surge peak on-state current	f = 50 Hz	t = 20 ms	110	А
TSM	(full cycle, T _J initial = 25°C)	f = 60 Hz	t = 16.7 ms	120	A
l²t	I ² t Value for fusing		t _p = 8.3 ms	60	A²s
di/dt	Critical rate of rise of on-state current f = 120 Hz		T _J = 110°C	70	A/µs
I _{gtm}	Peak gate trigger current $t_p \le 10 \ \mu s;$ $I_{cT} \le I_{GTM}$		T _J = 110°C	2.0	А
P _{G(AV)}	Average gate power dissipation T _J = 110°C			0.5	W
T _{stg}	Storage temperature range			-40 to 150	°C
Tj	Operating junction temperature range			-40 to 110	°C

Electrical Characteristics (T_j = 25°C, unless otherwise specified)

Symbol	Test Conditions Quadrar		rant	Qxx12LH1	Unit
I _{gt}	V 12V D 02 O	- -	MAX.	10	mA
V _{GT}	$V_{\rm D} = 12V R_{\rm L} = 60 \Omega$	- -	MAX.	1.3	V
V _{gd}	$V_{\rm D} = V_{\rm DRM} R_{\rm L} = 3.3 \text{ k}\Omega T_{\rm J} = 110^{\circ}\text{C}$ I – II – III		MIN.	0.2	V
I _H	I _T = 20mA		MAX.	8	mA
dv/dt	$V_{\rm D} = V_{\rm DRM}$ Gate Open $T_{\rm J} = 110^{\circ} \rm C$		MIN.	45	V/µs
(dv/dt)c	$(di/dt)c = 6.5 \text{ A/ms } T_{J} = 110^{\circ}\text{C}$		MIN.	2	V/µs
t _{gt}	$I_{g} = 2 \times I_{gT}$ PW = 15µs $I_{T} = 17.0$ A(pk)		TYP.	4	μs

Static Characteristics

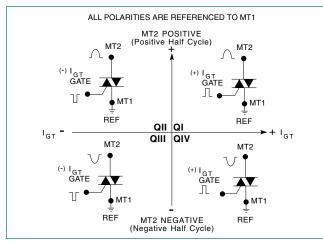
Symbol	Value	Unit			
V _{TM}	$I_{TM} = 17.0A t_{p} = 380 \ \mu s$		MAX.	1.60	V
I _{drm} I _{rrm}		$T_{J} = 25^{\circ}C$		10	μA
	$V_{\rm d} = V_{\rm drm} / V_{\rm rrm}$	T _J = 110°C	MAX.	1	mA

Thermal Resistances

Symbol	Parameter	Value	Unit
R _{θ(J-C)}	Junction to case (AC)	2.3	°C/W
R _{θ(J-A)}	Junction to ambient	55	°C/W



Figure 1: Definition of Quadrants



Note: Alternistors will not operate in QIV



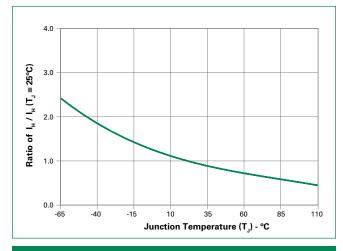


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

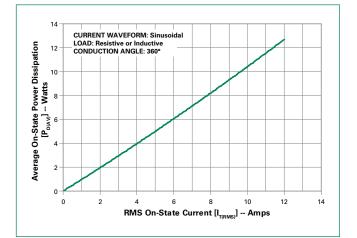
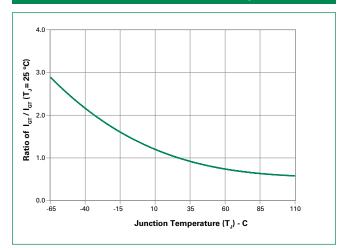


Figure 2: Normalized DC Gate Trigger Current for All Quadrants vs. Junction Temperature





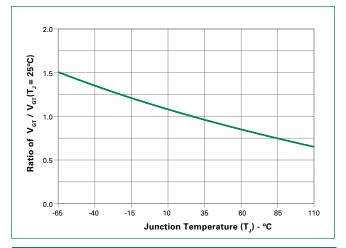


Figure 6: Maximum Allowable Case Temperature vs. On-State Current

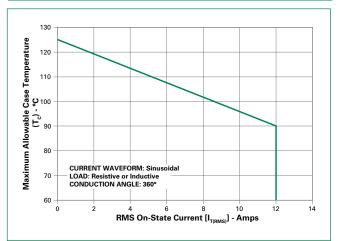




Figure 7: Maximum Allowable Ambient Temperature vs. On-State Current

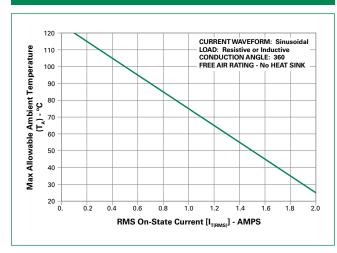


Figure 8: On-State Current vs. On-State Voltage (Typical)

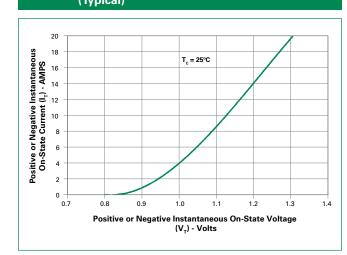
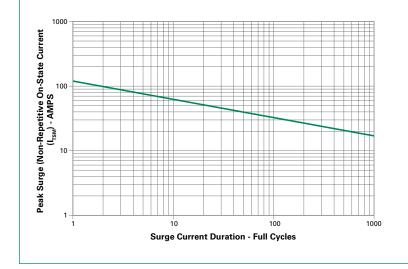


Figure 9: Surge Peak On-State Current vs. Number of Cycles



Supply Frequency: 60Hz Sinusoidal Load: Resistive RMS On-State Current [I _{TIRMS]} : Maximum] Rated Value at Specific Case Temperature

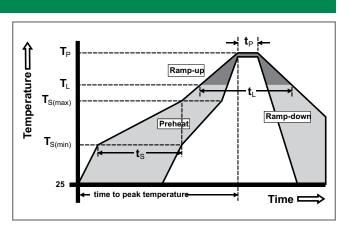
Notes:

- 1. Gate control may be lost during and immediately following surge current interval.
- Overload may not be repeated until junction temperature has returned to steady-state rated value.



Soldering Parameters

Reflow Condition		Pb – Free assembly	
	-Temperature Min (T _{s(min)})	150°C	
Pre Heat	-Temperature Max (T _{s(max)})	200°C	
	-Time (min to max) (t _s)	60 – 180 secs	
Average ramp up rate (LiquidusTemp) (T _L) to peak		5°C/second max	
T _{S(max)} to T _L - Ramp-up Rate		5°C/second max	
Reflow	-Temperature (T _L) (Liquidus)	217°C	
nellow	-Time (min to max) (t _s)	60 – 150 seconds	
PeakTemp	erature (T _P)	260 ^{+0/-5} °C	
Time within 5°C of actual peak Temperature (t _p)		20 – 40 seconds	
Ramp-down Rate		5°C/second max	
Time 25°C to peak Temperature (T _P)		8 minutes Max.	
Do not exc	ceed	280°C	



Physical Specifications					
Terminal Finish	100% Matte Tin-plated				
Body Material	UL recognized epoxy meeting flammability classification 94V-0				
Terminal Material	Copper Alloy				

Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

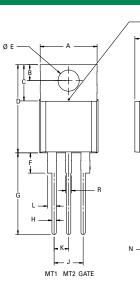
Environmental Specifications				
Test	Specifications and Conditions			
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 110°C for 1008 hours			
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell time			
Temperature/ Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity			
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C			
Low-Temp Storage	1008 hours; -40°C			
Thermal Shock	MIL-STD-750, M-1056 10 cycles; 0°C to 100°C; 5-min dwell time at each temperature; 10 sec (max) transfer time between temperature			
Autoclave	EIA / JEDEC, JESD22-A102 168 hours (121°C at 2 ATMs) and 100% R/H			
Resistance to Solder Heat	MIL-STD-750 Method 2031			
Solderability	ANSI/J-STD-002, category 3, Test A			
Lead Bend	MIL-STD-750, M-2036 Cond E			

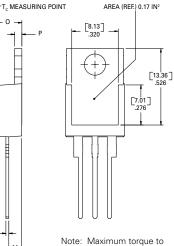
Environmental Specifications



Dimensions - TO-220AB (L-Package) - Isolated Mounting Tab

0





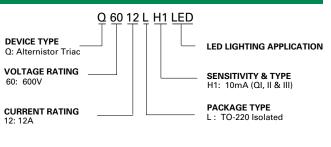
be applied to mounting tab is 8 in-lbs. (0.904 Nm).

Dimension	Inches		IVIIIImeters	
DIMENSION	Min Max		Min	Max
А	0.380	0.420	9.65	10.67
В	0.105	0.115	2.67	2.92
С	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
E	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
Н	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
М	0.085	0.095	2.16	2.41
Ν	0.018	0.024	0.46	0.61
0	0.178	0.188	4.52	4.78
Р	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

Product Selector					
	Gate Sensitivity Quadrants	Turce			
Part Number	I – II – III	Type F	Package		
Q6012LH1LED	10 mA	Alternistor Triac	TO-220L		

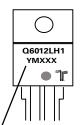
Packing Options					
	Part Number	Marking	Weight	Packing Mode	Base Quantity
	Q6012LH1LED	Q6012LH1	2.2 g	Bulk	500
	Q6012LH1LEDTP	Q6012LH1	2.2 g	Tube Pack	500 (50 per tube)

Part Numbering System



Part Marking System

TO-220 AB - (L Package)



Date Code Marking Y:Year Code M: Month Code XXX: Lot Trace Code

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